

FOD814 Series, FOD617 Series, FOD817 Series 4-Pin Phototransistor Optocouplers

Features

- AC input response (FOD814 only)
- Applicable to Pb-free IR reflow soldering
- Compact 4-pin package
- Current transfer ratio in selected groups:

FOD617A: 40–80%	FOD817: 50–600%
FOD617B: 63–125%	FOD817A: 80–160%
FOD617C: 100–200%	FOD817B: 130–260%
FOD617D: 160–320%	FOD817C: 200–400%
FOD814: 20–300%	FOD817D: 300–600%
FOD814A: 50–150%	
- C-UL, UL and VDE approved
- High input-output isolation voltage of 5000Vrms
- Higher operating temperatures (versus FODXXX counterparts)
- Minimum BV_{CEO} of 70V guaranteed

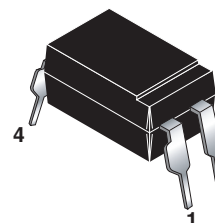
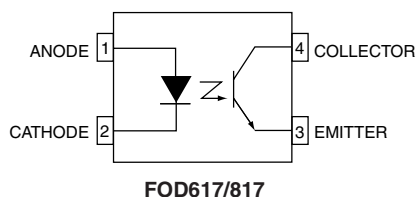
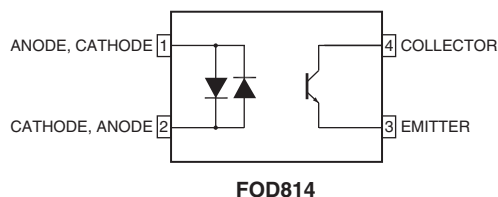
Applications

- FOD814 Series
- AC line monitor
 - Unknown polarity DC sensor
 - Telephone line interface
- FOD617 and FOD817 Series
- Power supply regulators
 - Digital logic inputs
 - Microprocessor inputs

Description

The FOD814 consists of two gallium arsenide infrared emitting diodes, connected in inverse parallel, driving a silicon phototransistor output in a 4-pin dual in-line package. The FOD617/817 Series consists of a gallium arsenide infrared emitting diode driving a silicon phototransistor in a 4-pin dual in-line package.

Functional Block Diagram



Absolute Maximum Ratings ($T_A = 25^\circ\text{C}$ Unless otherwise specified.)

Parameter	Symbol	Value		Units
		FOD814	FOD617/817	
TOTAL DEVICE				
Storage Temperature	T_{STG}	-55 to +150		$^\circ\text{C}$
Operating Temperature	T_{OPR}	-55 to +105	-55 to +110	$^\circ\text{C}$
Lead Solder Temperature	T_{SOL}	260 for 10 sec		$^\circ\text{C}$
Total Power Dissipation	P_{TOT}	200		mW
EMITTER				
Continuous Forward Current	I_F	± 50	50	mA
Reverse Voltage	V_R	—	6	
Power Dissipation Derate above 100°C	P_D	70 1.7		mW mW/ $^\circ\text{C}$
DETECTOR				
Collector-Emitter Voltage	V_{CEO}	70		V
Emitter-Collector Voltage	V_{ECO}	6	6 (FOD817) 7 (FOD617)	V
Continuous Collector Current	I_C	50		mA
Collector Power Dissipation Derate above 90°C	P_C	150 2.9		mW mW/ $^\circ\text{C}$

Electrical/Characteristics ($T_A = 25^\circ\text{C}$ Unless otherwise specified.)

Individual Component Characteristics

Parameter	Device	Test Conditions	Symbol	Min	Typ*	Max	Unit
EMITTER							
Forward Voltage	FOD814 FOD617 FOD817	($I_F = \pm 20\text{ mA}$) ($I_F = 60\text{ mA}$) ($I_F = 20\text{ mA}$)	V_F	— — —	1.2 1.35 1.2	1.4 1.65 1.4	V
Reverse Leakage Current	FOD617 FOD817	($V_R = 6.0\text{ V}$) ($V_R = 4.0\text{ V}$)	I_R	— —	0.001 —	10 10	μA
Terminal Capacitance	FOD814 FOD617 FOD817	($V = 0, f = 1\text{ kHz}$) ($V = 0, f = 1\text{ kHz}$) ($V = 0, f = 1\text{ kHz}$)	C_t	— — —	50 30 30	250 250 250	pF
DETECTOR							
Collector Dark Current	FOD814 FOD617C/ D FOD617A/ B FOD817	($V_{CE} = 20\text{ V}, I_F = 0$) ($V_{CE} = 10\text{ V}, I_F = 0$) ($V_{CE} = 10\text{ V}, I_F = 0$) ($V_{CE} = 20\text{ V}, I_F = 0$)	I_{CEO}	— — — —	— 1 1 —	100 100 50 100	nA
Collector-Emitter Breakdown Voltage	FOD814 FOD617 FOD817	($I_C = 0.1\text{ mA}, I_F = 0$) ($I_C = 100\text{ }\mu\text{A}, I_F = 0$) ($I_C = 0.1\text{ mA}, I_F = 0$)	BV_{CEO}	70 70 70	— — —	— — —	V
Emitter-Collector Breakdown Voltage	FOD814 FOD617 FOD817	($I_E = 10\text{ }\mu\text{A}, I_F = 0$) ($I_E = 10\text{ }\mu\text{A}, I_F = 0$) ($I_E = 10\text{ }\mu\text{A}, I_F = 0$)	BV_{ECO}	6 7 6	— — —	— — —	V

Transfer Characteristics ($T_A = 25^\circ\text{C}$ Unless otherwise specified.)

DC Characteristic	Device	Test Conditions	Symbol	Min	Typ*	Max	Unit
Current Transfer Ratio	FOD814	$I_F = \pm 1\text{ mA}, V_{CE} = 5\text{ V}^1$	CTR	20	—	300	%
	FOD814A			50	—	150	
	FOD617A	$I_F = 10\text{ mA}, V_{CE} = 5\text{ V}^1$		40	—	80	
	FOD617B			63	—	125	
	FOD617C			100	—	200	
	FOD617D			160	—	320	
	FOD617A	$I_F = 1\text{ mA}, V_{CE} = 5\text{ V}^1$		13	—	—	
	FOD617B			22	—	—	
	FOD617C			34	—	—	
	FOD617D			56	—	—	
	FOD817	$I_F = 5\text{ mA}, V_{CE} = 5\text{ V}^1$		50	—	600	
	FOD817A			80	—	160	
	FOD817B			130	—	260	
	FOD817C			200	—	400	
	FOD817D			300	—	600	
Collector-Emitter Saturation Voltage	FOD814	$I_F = \pm 20\text{ mA}, I_C = 1\text{ mA}$	$V_{CE(sat)}$	—	0.1	0.2	V
	FOD617	$I_F = 10\text{ mA}, I_C = 2.5\text{ mA}$		—	—	0.4	
	FOD817	$I_F = 20\text{ mA}, I_C = 1\text{ mA}$		—	0.1	0.2	
Cut-Off Frequency	FOD814	$V_{CE} = 5\text{ V}, I_C = 2\text{ mA}, R_L = 100\text{ }\Omega, -3\text{ dB}$	f_C	15	80	—	KHz

*Typical values at $T_A = 25^\circ\text{C}$

Transfer Characteristics (continued) ($T_A = 25^\circ\text{C}$ Unless otherwise specified.)

AC Characteristic	Device	Test Conditions	Symbol	Min	Typ*	Max	Unit
Response Time (Rise)	FOD814 FOD617 FOD817	$V_{CE} = 2\text{ V}, I_C = 2\text{ mA}, R_L = 100\ \Omega^2$	t_r	—	4	18	μs
Response Time (Fall)	FOD814 FOD617 FOD817		t_f	—	3	18	μs

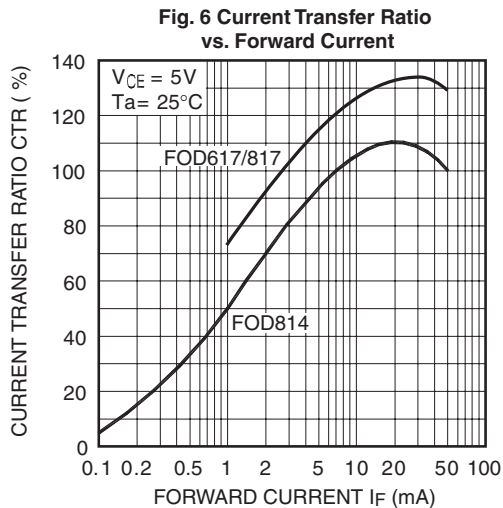
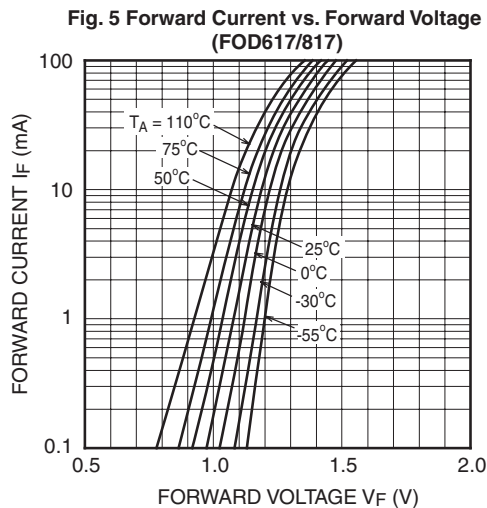
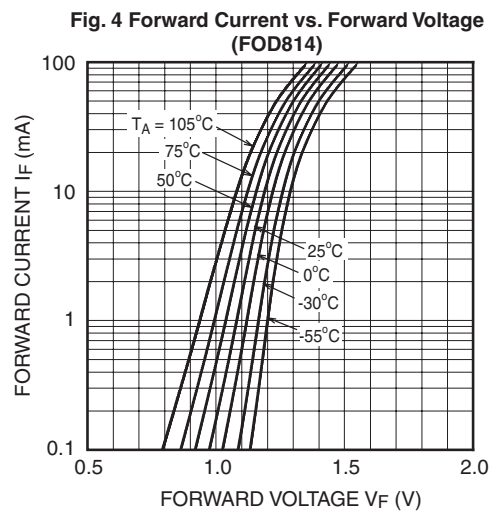
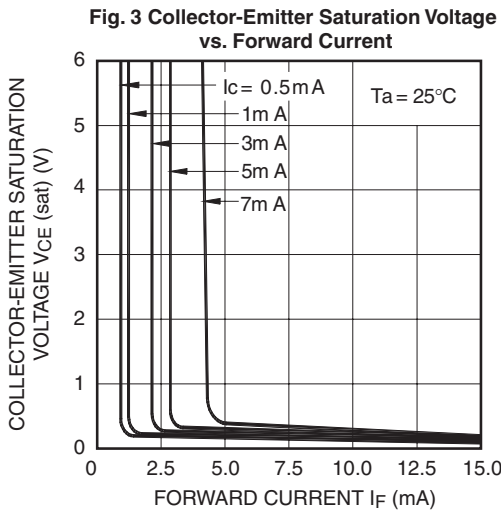
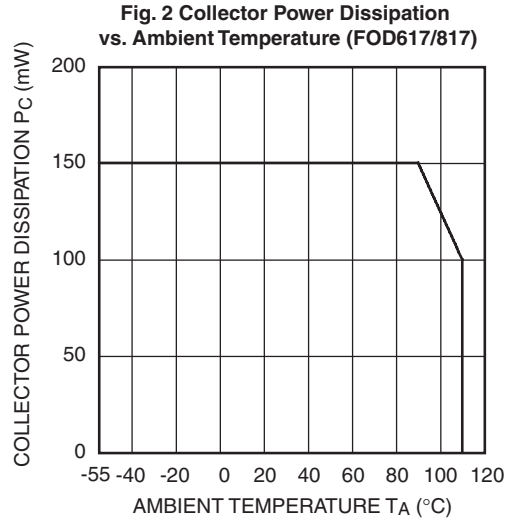
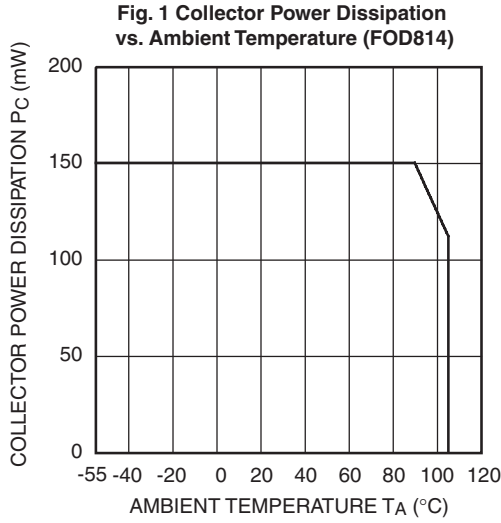
Isolation Characteristics

Characteristic	Device	Test Conditions	Symbol	Min	Typ*	Max	Units
Input-Output Isolation Voltage ³	FOD814	$f = 60\text{ Hz}, t = 1\text{ min}$	V_{ISO}	5000			Vac(rms)
	FOD617						
	FOD817						
Isolation Resistance	FOD814	$V_{I-O} = 500\text{ VDC}$	R_{ISO}	5×10^{10}	1×10^{11}	—	Ω
	FOD617						
	FOD817						
Isolation Capacitance	FOD814	$V_{I-O} = 0, f = 1\text{ MHz}$	C_{ISO}		0.6	1.0	pf
	FOD617						
	FOD817						

*Typical values at $T_A = 25^\circ\text{C}$ **Notes**

1. Current Transfer Ratio (CTR) = $I_C/I_F \times 100\%$.
2. For test circuit setup and waveforms, refer to page 4.
3. For this test, Pins 1 and 2 are common, and Pins 3 and 4 are common.

Typical Electrical/Optical Characteristic Curves ($T_A = 25^\circ\text{C}$ Unless otherwise specified.)



Typical Electrical/Optical Characteristic Curves ($T_A = 25^\circ\text{C}$ Unless otherwise specified.)

Fig. 7 Collector Current vs. Collector-Emitter Voltage (FOD814)

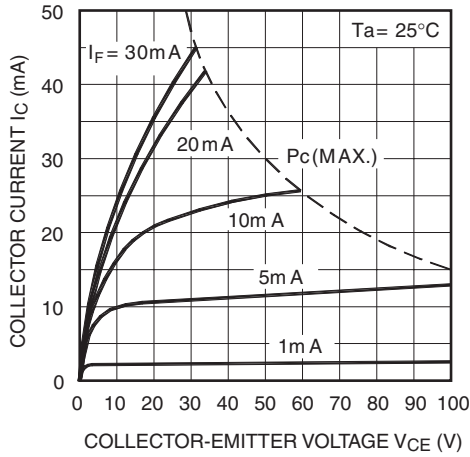


Fig. 8 Collector Current vs. Collector-Emitter Voltage (FOD617/817)

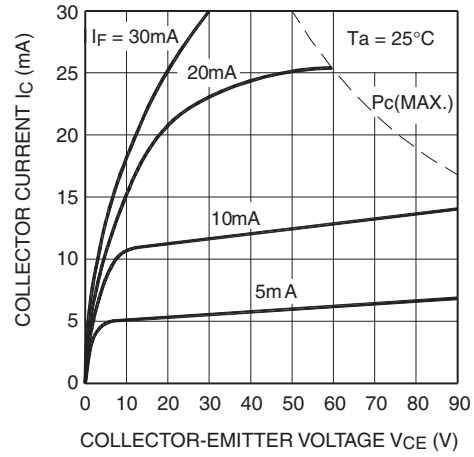


Fig. 9 Relative Current Transfer Ratio vs. Ambient Temperature

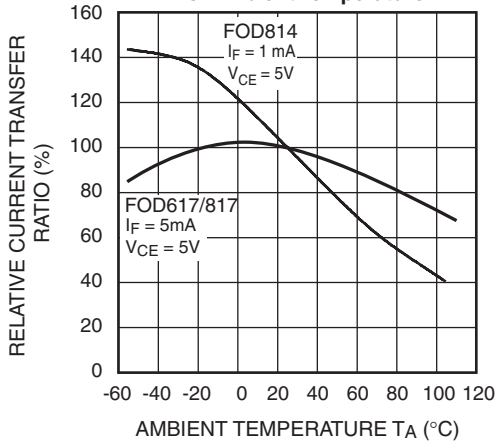


Fig. 10 Collector-Emitter Saturation Voltage vs. Ambient Temperature

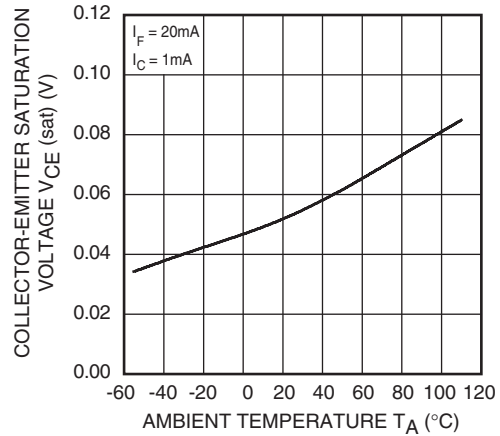


Fig. 11 LED Power Dissipation vs. Ambient Temperature (FOD814)

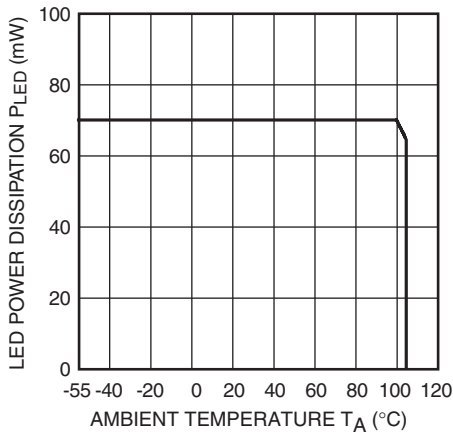
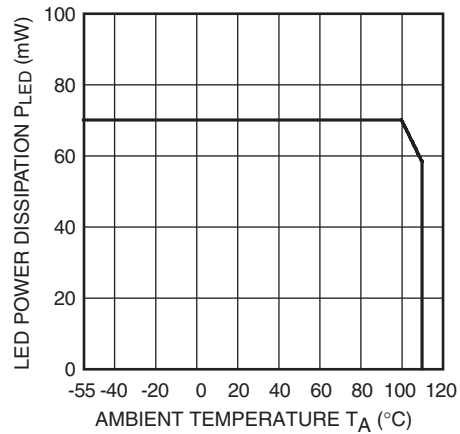


Fig. 12 LED Power Dissipation vs. Ambient Temperature (FOD617/817)



Typical Electrical/Optical Characteristic Curves ($T_A = 25^\circ\text{C}$ Unless otherwise specified.)

Fig. 13 Response Time vs. Load Resistance

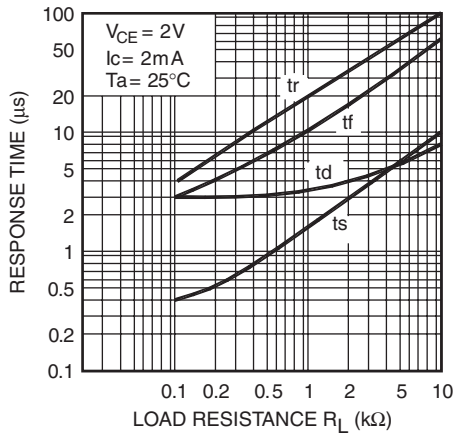


Fig. 14 Frequency Response

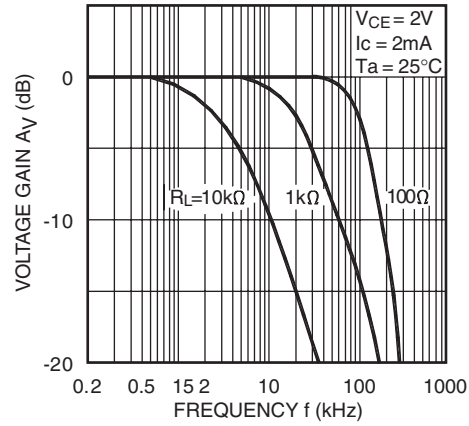
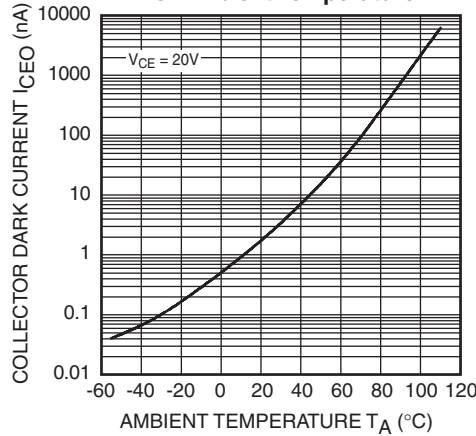
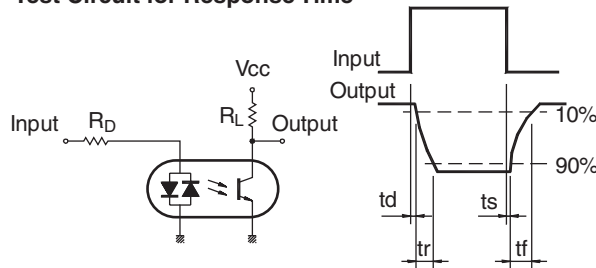


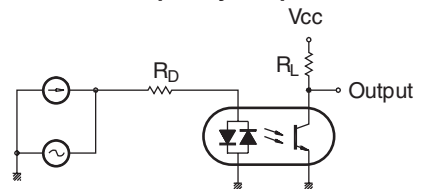
Fig. 15 Collector Dark Current vs. Ambient Temperature



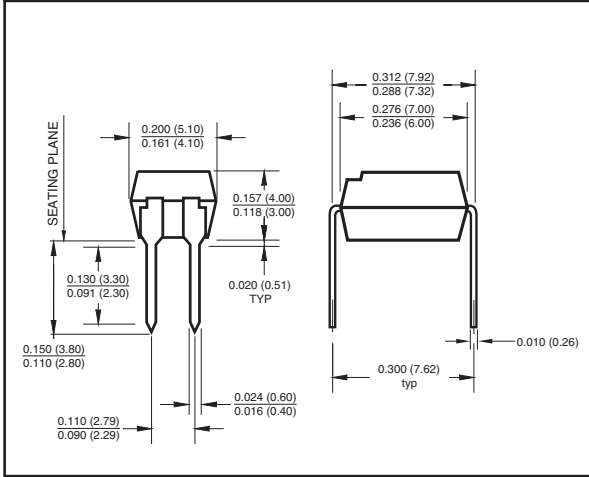
Test Circuit for Response Time



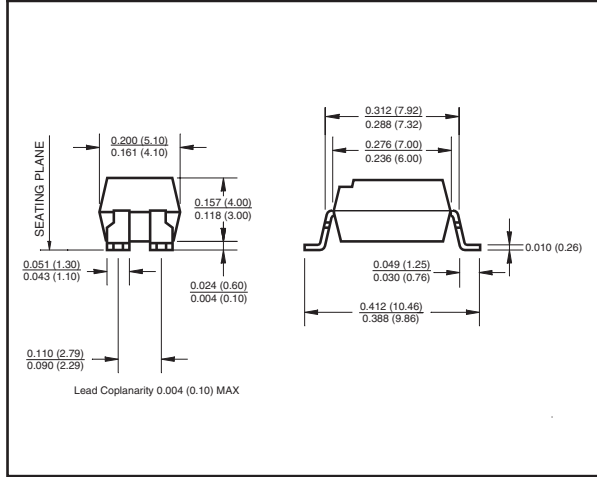
Test Circuit for Frequency Response



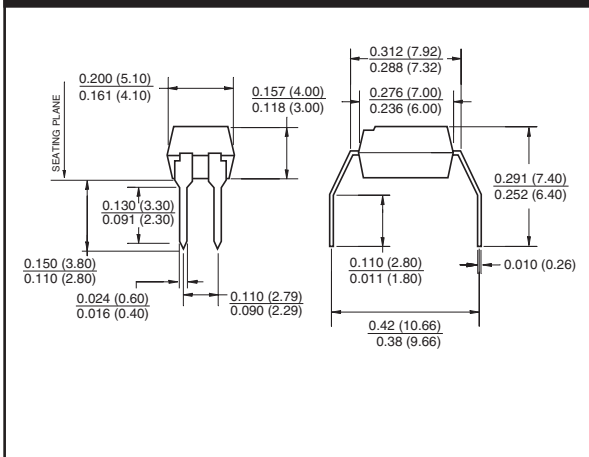
Package Dimensions (Through Hole)



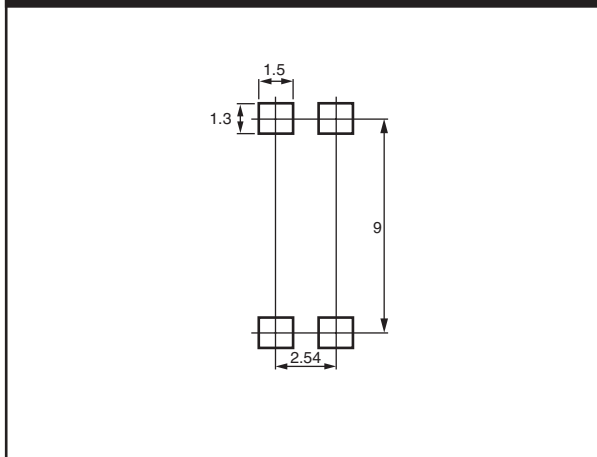
Package Dimensions (Surface Mount)



Package Dimensions (0.4" Lead Spacing)



Footprint Dimensions (Surface Mount)



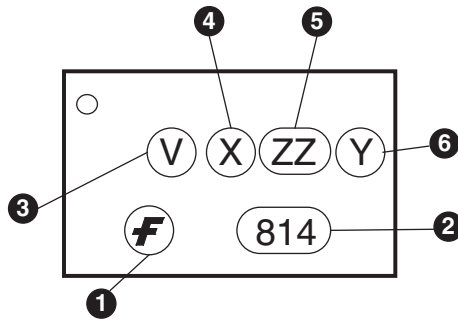
NOTE

All dimensions are in inches (millimeters)

Ordering Information

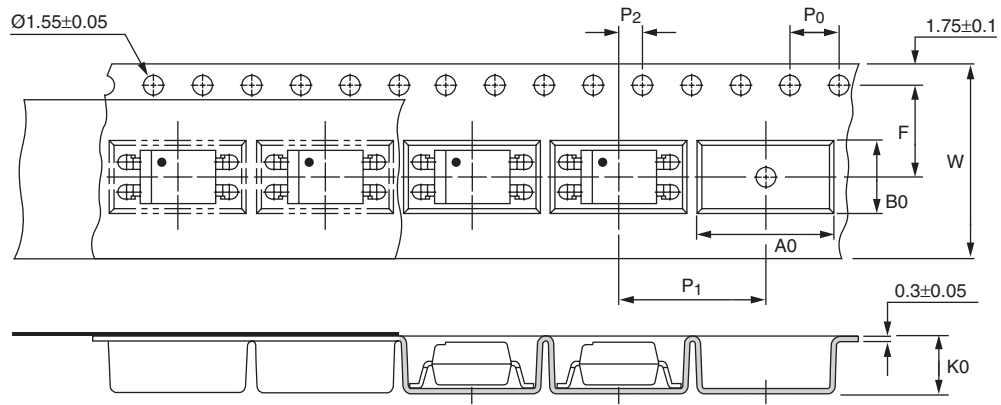
Option	Part Number Example	Description
S	FOD814S	Surface Mount Lead Bend
SD	FOD814SD	Surface Mount; Tape and reel
W	FOD814W	0.4" Lead Spacing
300	FOD814300	VDE Approved
300W	FOD814300W	VDE Approved, 0.4" Lead Spacing
3S	FOD8143S	VDE Approved, Surface Mount
3SD	FOD8143SD	VDE Approved, Surface Mount, Tape & Reel

Marking Information



Definitions	
1	Fairchild logo
2	Device number
3	VDE mark (Note: Only appears on parts ordered with VDE option – See order entry table)
4	One digit year code
5	Two digit work week ranging from '01' to '53'
6	Assembly package code

Carrier Tape Specifications

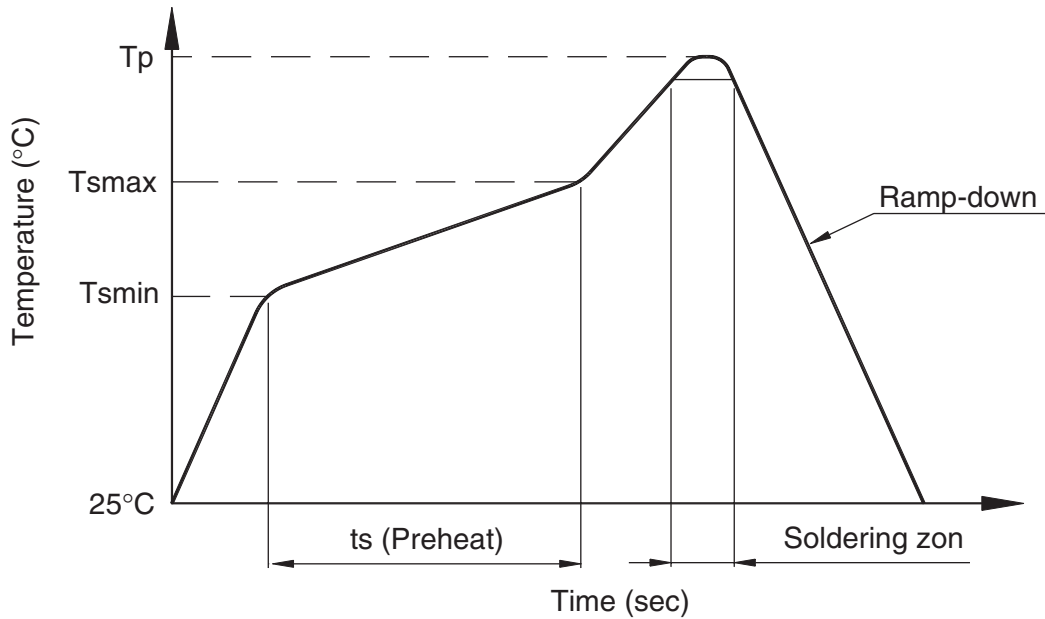


NOTE

All dimensions are in millimeters

Description	Symbol	Dimensions in mm (inches)
Tape wide	W	16 ± 0.3 (.63)
Pitch of sprocket holes	P_0	4 ± 0.1 (.15)
Distance of compartment	F	7.5 ± 0.1 (.295)
	P_2	2 ± 0.1 (.079)
Distance of compartment to compartment	P_1	12 ± 0.1 (.472)
Compartment	A_0	10.45 ± 0.1 (.411)
	B_0	5.30 ± 0.1 (.209)
	K_0	4.25 ± 0.1 (.167)

Lead Free recommended IR Reflow condition



Profile Feature	Pb-Sn solder assembly	Lead Free assembly
Preheat condition (Tsmmin-Tsmmax / ts)	100°C ~ 150°C 60 ~ 120 sec	150°C ~ 200°C 60 ~ 120 sec
Melt soldering zone	183°C 60 ~ 120 sec	217°C 30 ~ 90 sec
Peak temperature (Tp)	240 +0/-5°C	260 +0/-5°C
Ramp-down rate	6°C/sec max.	6°C/sec max.

Recommended Wave Soldering condition

Profile Feature	For all solder assembly
Peak temperature (Tp)	Max 260°C for 10 sec

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DOME™	HiSeC™	MSX™	RapidConfigure™	UHC™
EcoSPARK™	I ² C™	MSXPro™	RapidConnect™	UltraFET®
E ² CMOS™	i-Lo™	OCX™	μSerDes™	UniFET™
EnSigna™	ImpliedDisconnect™	OCXPro™	ScalarPump™	VCX™
FACT™	IntelliMAX™	OPTOLOGIC®	SILENT SWITCHER®	Wire™
FACT Quiet Series™		OPTOPLANAR™	SMART START™	
Across the board. Around the world.™		PACMAN™	SPM™	
The Power Franchise®		POP™	Stealth™	
Programmable Active Droop™		Power247™	SuperFET™	
		PowerEdge™	SuperSOT™-3	

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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